

Surface Mount Schottky Barrier Rectifier
Reverse Voltage - 20 to 200 V
Forward Current - 8 A
FEATURES

- ◆Metal silicon junction, majority carrier conduction
- ◆For surface mounted applications
- ◆Low power loss, high efficiency
- ◆High forward surge current capability
- ◆For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: DO-214AA/SMB
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 0.095g / 0.003oz

Absolute Maximum Ratings and Electrical characteristics
Ratings at 25 °C ambient temperature unless otherwise specified.Single phase, half wave,
60Hz resistive or inductive load,for capacitive load, derate by 20 %

Pinning

1.Cathode	2.Anode
	
DO-214AA/SMB	

Marking Code

SS82B	YFW SS82
SS84B	YFW SS84
SS86B	YFW SS86
SS88B	YFW SS88
SS810B	YFW SS810
SS812B	YFW SS812
SS815B	YFW SS815
SS820B	YFW SS820

Parameter	Symbols	SS82B	SS84B	SS86B	SS88B	SS810B	SS812B	SS815B	SS820B	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	I_{F(AV)}	8.0								A
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120								A
Peak Forward Surge Current,1.0ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	240								A
I ² t Rating for fusing (3ms≤t≤8.3ms)	I²t	59.7								A²S
Maximum Instantaneous Forward Voltage at 8 A	V_F	0.55		0.70	0.85		0.95			V
Maximum Instantaneous Reverse Current T _A = 25°C at Rated DC Reverse Voltage T _A = 100°C	I_R	1.0 50								mA
Typical Junction Capacitance ⁽¹⁾	C_j	270		220	160		100		80	pF
Typical Thermal Resistance ⁽²⁾	R_{θJA} R_{θJC} R_{θJL}	100 20 25								°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

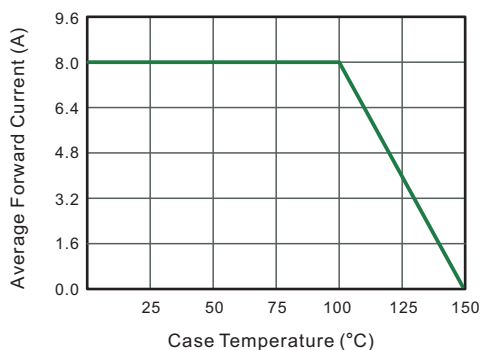


Fig.2 Typical Reverse Characteristics

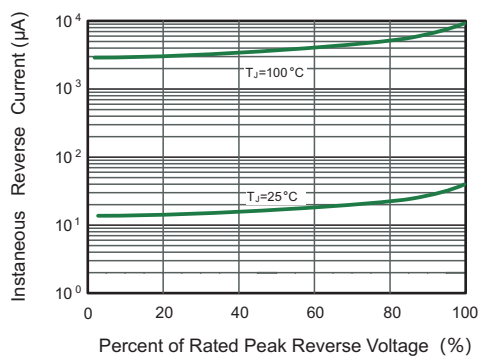


Fig.3 Typical Forward Characteristic

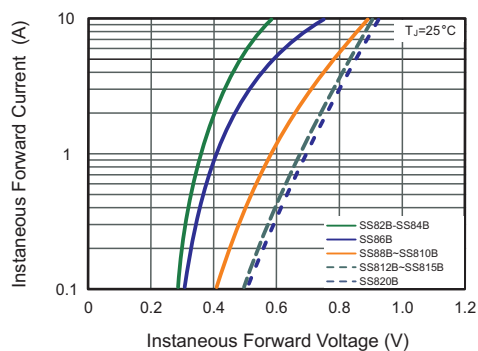


Fig.4 Typical Junction Capacitance

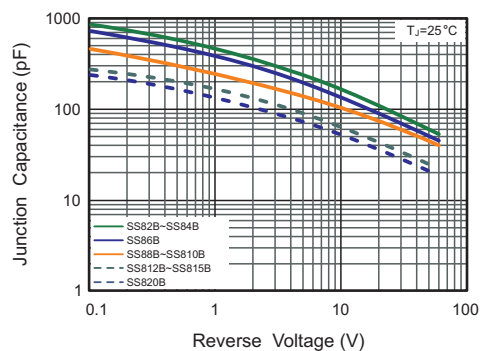
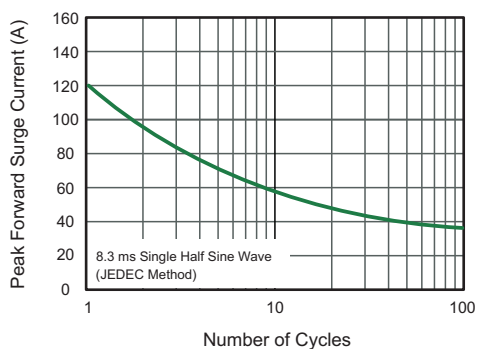
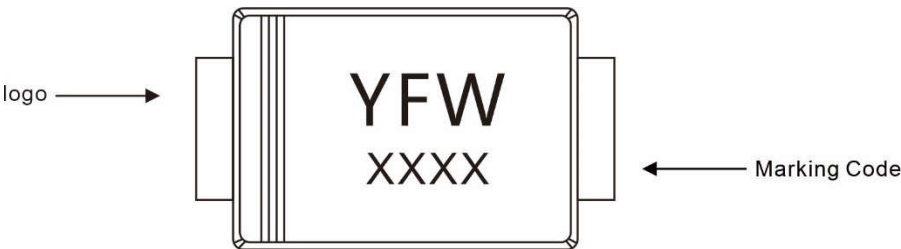


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



Marking Diagram



Ordering information

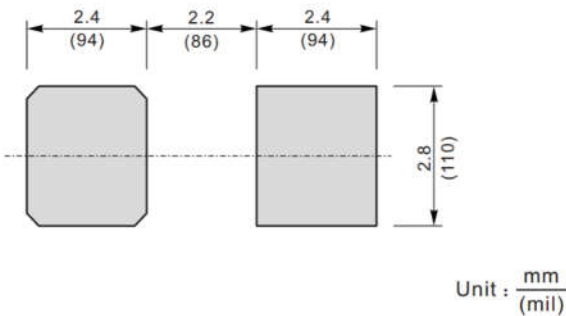
Package	Packing Description	Packing Quantity
DO-214AA SMB	Tape/Reel, 13"reel	3000PCS/Reel 30000PCS/Carton

Package Dimensions

DO-214AA SMB

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	2.13	2.44	84	96
E	4.06	4.70	160	185
D	3.3	3.94	130	155
E ₁	5.08	5.59	200	220
A ₁	0.05	0.20	2.0	7.9
L	0.8	1.5	32	59
C	0.152	0.305	6	12
b	1.9	2.2	75	87

The recommended mounting pad size



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